# MSKSEMI 美森科













**ESD** 

3

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PLED

# **MSNCP1529ASNT1G**

**Product specification** 





#### **GENERAL DESCRIPTION**

The MSNCP1529ASNT1G is a compact 5V Buck Converter which can deliver 1A output current.

MSNCP1529ASNT1G employs a proprietary control loop to achieve a fast transient load response. It keeps high converting efficiency in both light load and heavy load.

MSNCP1529ASNT1G is equipped with all kinds of protection, such as input over voltage protection, output short circuit protection, over current protection and over temperature protection.

MSNCP1529ASNT1G is consists of internal power tree generator, bandgap voltage reference module, under-voltage-lockout (UVLO) module, error amplifier, protection circuitry, driver block, current sensing block and two power MOSFETs.

MSNCP1529ASNT1G is housed in a SOT23-5 package.

#### **FEATURES**

- Input operation range: 2.2–5.5V
- Input over voltage protection at 6V
- 30uA quiescent current in operation
- Output current up to 1A
- Efficiency up to 95%
- OCP, SCP and OTP protection
- SOT23-5 package

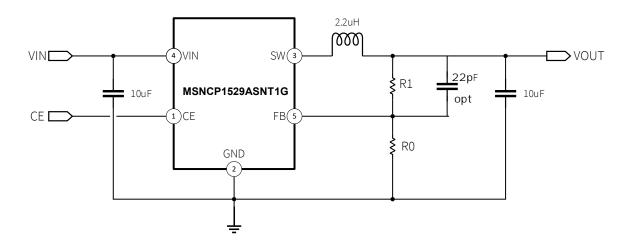
## **Applications**

- Set-top Box
- Solid State Drive
- WIFI and Network Devices
- Security surveillance system
- Toys
- TV
- All other electronic devices

#### **Reference News**

Type No	SOT-23-5	MARKING	
MSNCP1529ASNT1G		A1**	

## **Typical Application Circuit**

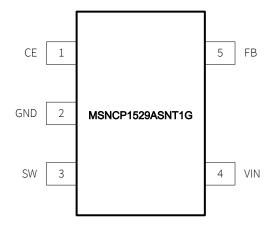




### **ORDER INFORMATION**

P/N	PKG	QTY
MSNCP1529ASNT1G	SOT-23-5	3000

## Pin Assignment



The package of MSNCP1529ASNT1G is SOT-23-5 , with pin assignment shown in following table:

Pin No	Name	Description	
1	CE	Chip enable pin, pull high to turn on the chip	
2	GND	Ground	
3	SW	The switching node, connecting a 2.2uH inductor to this node	
4	VIN	The input power node, connecting a 10uF capacitor to ground.	
5	FB	Feedback node, with Vfb at 0.6V	



## **Absolute Maximum Ratings**

V <sub>IN</sub> <sup>(1)</sup>	0.3V to 6V
V <sub>OUT</sub> <sup>(1)</sup>	0.3V to 5.5V
Continuous Power Dissipation $(T_A = 25^{\circ}C)^{(2)}$	
SOT-23-5	0.4W
Junction Temperature	40°C to 125°C
Lead Temperature	260°C
Storage Temperature	65°C to +150°C
Thermal Resistance (3)	$oldsymbol{ heta}_{ extsf{JA}}$ $oldsymbol{ heta}_{ extsf{JC}}$
SOT-23- <b>5</b>	170°C /W75°C /W

#### Notes:

- (1) Exceeding these ratings may damage the device.
- (2) The maximum allowable power dissipation is a function of the maximum junction temperature T<sub>J</sub>(MAX), the junction-to-ambient thermal resistance θ<sub>JA</sub>, and the ambient temperature T<sub>A</sub>. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P<sub>D</sub>(MAX)=(T<sub>J</sub>(MAX)-T<sub>A</sub>)/θ<sub>JA</sub>. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- (3) Measured on JESD51-7, 4-layer PCB.

#### **Electrical Characteristics**

All typical values are at Tj=25°C (unless otherwise noted)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input voltage range, V <sub>IN</sub>		2.2		5.5	V
Input over voltage protection		5.8	6	6.5	V
Quiescent current, IQ	$V_{IN} = 5V$	20	30	60	μΑ
Shutdown current, loff	$V_{IN} = 5V$ , $V_{CE} = 0$		0.1	2	μΑ
Input voltage LIVI O	Rising		2.55	2.65	V
Input voltage UVLO	Falling	2.25 2.37		V	
Feedback voltage	$V_{IN} = 5V$	0.588	0.6	0.612	V
Output current Limit	$V_{IN} = 5V, V_{OUT} = 3.3V$	1	1.2		А
Line regulation	$V_{IN} = 3 \text{ to } 5V$		0.2		%/V
Load regulation	I <sub>OUT</sub> = 0.1 – 1A		0.1	2	%/A
Switching frequency	$V_{IN} = 5V$	1	1.5	2	MHz
ON resistance PMOS	$V_{IN} = 5V$		0.38		Ω
ON resistance NMOS	$V_{IN} = 5V$		0.25		Ω
CE input threshold ON	$V_{IN} = 5V$		0.9	1.1	V
CE input threshold OFF	$V_{IN} = 5V$	0.4	0.7		V
CE input pull down resistor			750		ΚΩ
Output discharge resistor, R <sub>pd</sub>	$V_{IN} = 5V$		600		Ω
Over temperature protection			150		°C
OTP hysteresis			40		°C



## **Application Information**

#### **Output Voltage Setting**

MSNCP1529ASNT1G 's feedback voltage is set at 0.6V, and it requires a resistor from FB node to ground, named R0, which is suggeste d to be less than 120K. Assuming the resistor between output node and FVB node is R1, the output voltage of DC-DC converting syst e m is given by

$$Vout = \frac{0.6V}{R0} \times (R1+R0)$$

#### Capacitor Selection

MSNCP1529ASNT1G requires one minimal 10uF MLCC capacitor at VIN node and one 10uF MLCC capacitor at VOUT node, however, it is alw a ys recommended to have two 10uF MLCC capacitors placed in parallel both at VIN and VOUT node to minimize the noise and withstand the current surge. It is also essential to place both input capacitors and output capacitors as close to MSME3103AM5G's VIN p in and VOUT pin as possible. An PCB layout example is shown at PCB layout recommendation section.

#### **Inductor Selection**

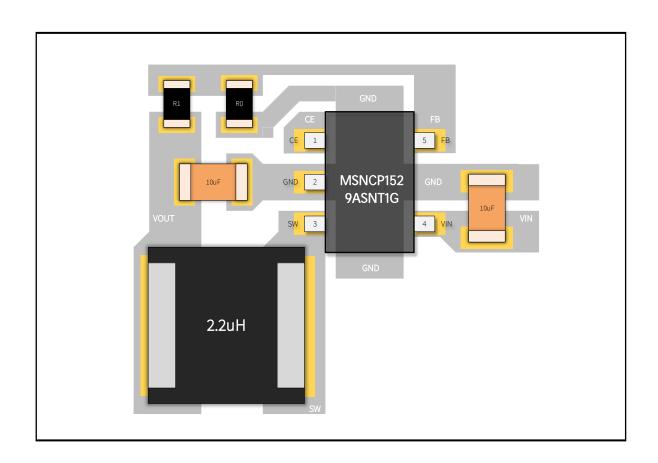
MSNCP1529ASNT1G works at a 1.5MHz oscillating frequency which helps to have a small voltage ripple at output. And 2.2uH inductor is fo und the most suitable value while meeting requirements on small output voltage ripple as well as a high-power conversion efficiency.

#### Thermal Considerations

Though MSNCP1529ASNT1G is a high efficiency DC/DC converter, there will always be some power lost during conversion, most of which be comes heat to make junction temperature higher. PCB design to ensure a good heat dissipation is important. Because the heat dissipation of the SOT-23-5 package is conducted through the pin No. 2, which is GND node of MSNCP1529ASNT1G, please make sure the ground plate of PCB is big enough to carry away the heat generated in the chip.

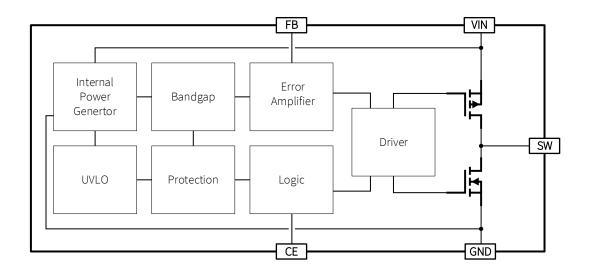
#### **PCB Layout**

An illustration of PCB layout recommendation with key elements is laid out as following. Please follow this PCB instruction to place the key peripheral devices such as input capacitors, output capacitors and inductor. And star-like connection for ground node is essential. And keeping power loop area as small as possible will improve the EMI performance.



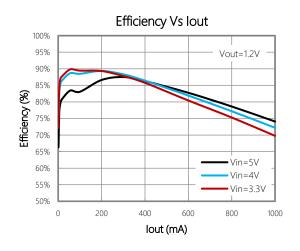


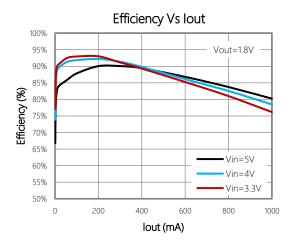
## **Block Diagram**



## **Typical Characteristics**

 $C_{IN}=C_{OUT}=10$ uF,  $T_A=25$ °C, unless otherwise specified

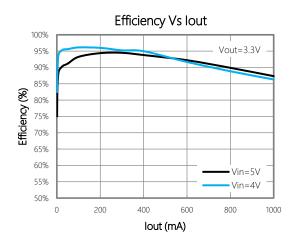


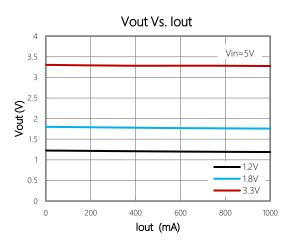


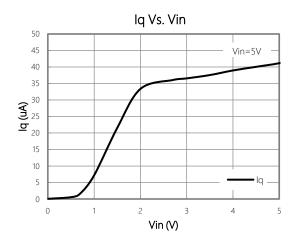


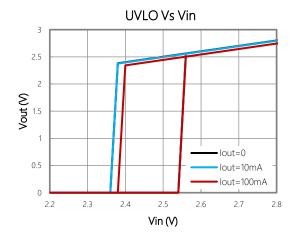
## Typical Characteristics (cont')

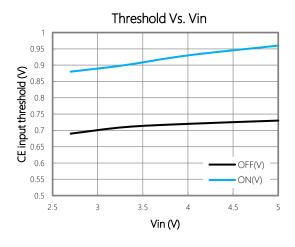
 $C_{IN}=C_{OUT}=10$ uF,  $T_A=25$ °C, unless otherwise specified

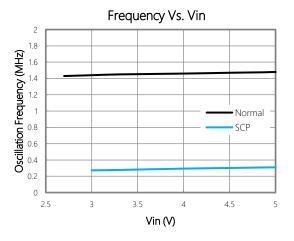












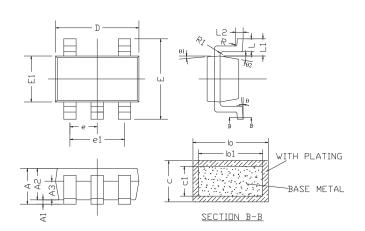


# Package Outline

Package SOT-23-5

Devices per reel

Package dimension (mm):



Symbol	MIN	NORM	MAX
А	-	-	1.25
A1	0.00	-	0.15
A2	1.00	1.10	1.20
А3	0.60	0.65	0.70
b	0.36	-	0.50
b1	0.36	0.38	0.45
С	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
Е	2.60	2.80	3.00
E1	1.526	1.626	1.726
е	0.90	0.95	1.00
e1	1.80	1.90	2.00
L	0.35	0.45	0.60
L1	0.59 REF		
L2	0.25 BSC		
R	0.05	-	-
R1	0.05	-	0.20
Θ	0°	-	8°
Θ1	3°	5°	7°
<b>Θ</b> 2	6°	-	14°



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